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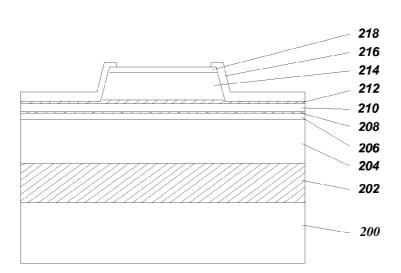
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[Continued on next page]

(54) Title: STRUCTURE AND METHOD FOR ACHIEVING SELECTIVE ETCHING IN (Ga,Al,In,B)N LASER DIODES



(57) Abstract: A structure and method that can be used to achieve selective etching in (Ga,Al,In,B)N laser diodes, comprising fabricating (Ga,Al,In,B)N laser diodes with one or more Al-containing etch stop layers.



FIG. 2A

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